

TMA20x Series

Triac (Bidirectional Triode Thyristor)

Selection Guide

Part Number	V _{DRM} (V)	UL-Recognized Component	Package	Packing
TMA204(I)	400	Yes	3-pin fully molded SIP with heatsink mount	50 pieces per tube
TMA204S-L	400	—		
TMA206(I)	600	Yes		
TMA206S-L	600	—		

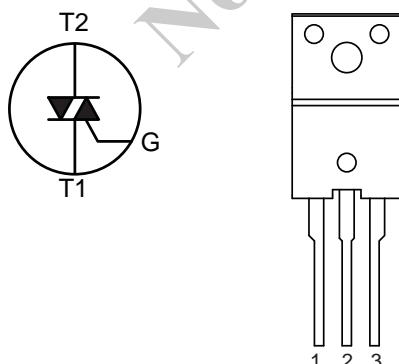
Absolute Maximum Ratings

Characteristic	Symbol	Notes		Rating	Units
Peak Repetitive Off-State Voltage	V _{DRM}	TMA204x	R _{GREF} = ∞	400	V
		TMA206x		600	V
Peak Non-Repetitive Off-State Voltage	V _{DSM}	TMA204x	R _{GREF} = ∞	500	V
		TMA206x		700	V
Isolation Voltage	V _{ISO}	AC RMS applied for 1 minute between lead and case		1800	V
RMS On-State Current	I _{T(RMS)}	50/60 Hz full cycle sine wave, total Conduction angle (α+) + (α-) = 360°, T _C = 53°C		20	A
Surge On-State Current	I _{TSM}	f = 60 Hz	Full cycle sine wave, peak value, non-repetitive, initial T _J = 125°C	200	A
		f = 50 Hz		190	A
I ² t Value for Fusing	I ² t	Value for 50 Hz half cycle sine wave, 1 cycle, I _{TSM} = 190 A		180	A ² •s
Peak Gate Current	I _{GM}	f ≥ 50 Hz, duty cycle ≤ 10%		2	A
Peak Gate Power Dissipation	P _{GM}	f ≥ 50 Hz, duty cycle ≤ 10%		5	W
Average Gate Power Dissipation	P _{GM(AV)}	T _J < T _{J(max)}		0.5	W
Junction Temperature	T _J			−40 to 125	°C
Storage Temperature	T _{sta}			−40 to 125	°C

Thermal Characteristics May require derating at maximum conditions

Characteristic	Symbol	Test Conditions	Value	Units
Package Thermal Resistance (Junction to Case)	R _{θJC}	For AC	3.2	°C/W

Pin-out Diagram



Terminal List Table

Number	Name	Function
1	T1	Main terminal, gate referenced
2	T2	Main terminal connect to signal side
3	G	Gate control

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, T_A, of 25°C, unless otherwise stated.

TMA20x
Series

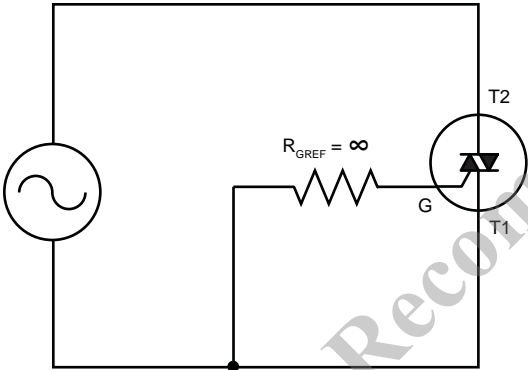
Triac (Bidirectional Triode Thyristor)

ELECTRICAL CHARACTERISTICS

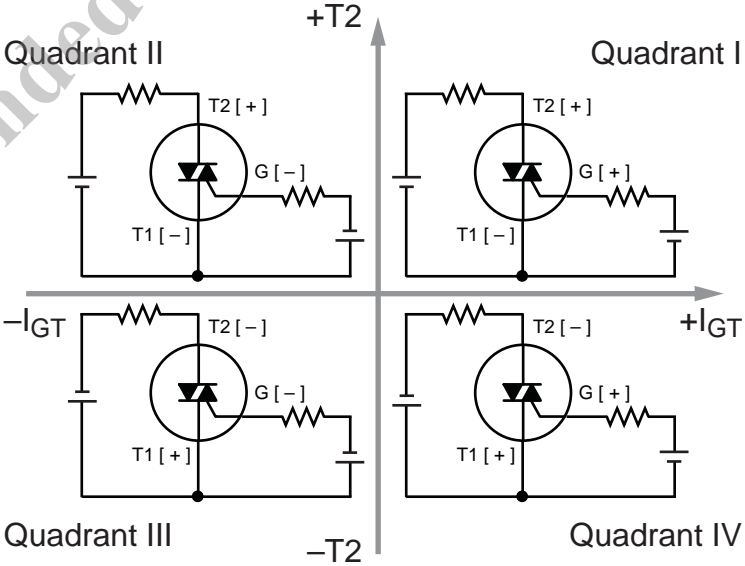
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Off-State Leakage Current	I_{DRM}	$V_D = V_{DRM}$, $T_J = 125^{\circ}C$, $R_{GREF} = \infty$ using test circuit 1	–	–	2.0	mA
		$V_D = V_{DRM}$, $T_J = 25^{\circ}C$, $R_{GREF} = \infty$ using test circuit 1	–	–	100	μA
On-State Voltage	V_{TM}	$I_T = 20\text{ A}$, $T_J = 25^{\circ}C$	–	–	1.5	V
Gate Trigger Voltage	V_{GT}	Quadrant I: T2+, G+	–	–	1.5	V
		Quadrant II: T2+, G–	–	–	1.5	V
		Quadrant III: T2–, G–	–	–	1.5	V
Gate Trigger Current	I_{GT}	Quadrant I: T2+, G+	–	–	30	mA
		Quadrant II: T2+, G–	–	–	30	mA
		Quadrant III: T2–, G–	–	–	30	mA
Gate Non-trigger Voltage	V_{GD}	$V_D = V_{DRM} \times 0.5$, $R_L = 4\text{ k}\Omega$, $T_J = 125^{\circ}C$	0.2	–	–	V
Critical Rising Rate of Off-State Voltage during Commutation*	$(dv/dt)_c$	$T_J = 125^{\circ}C$, $V_D = 400\text{ V}$, $(di/dt)_c = -10\text{ A/ms}$, $I_{TP} = 2\text{ A}$	10	–	–	V/ μs

*Where I_{TP} is the peak current through T2 to T1.

Test Circuit 1

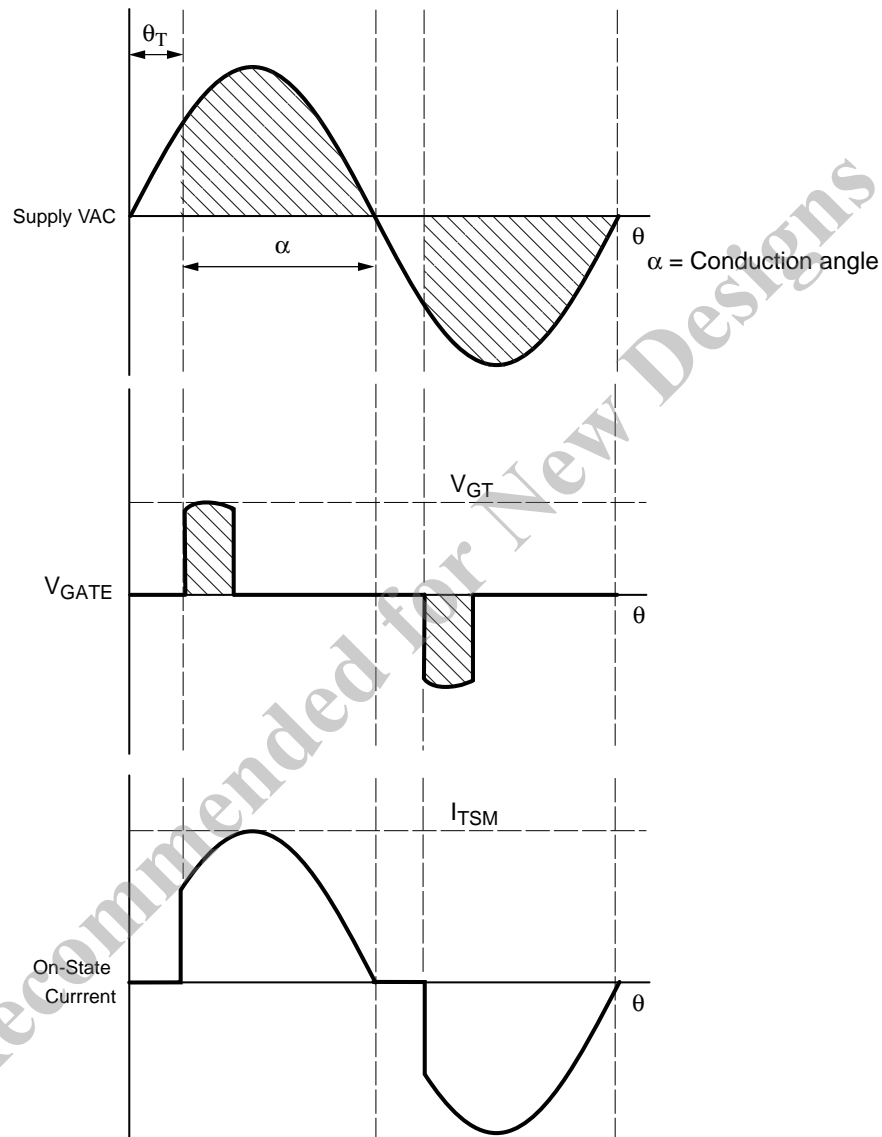


Gate Trigger Characteristics

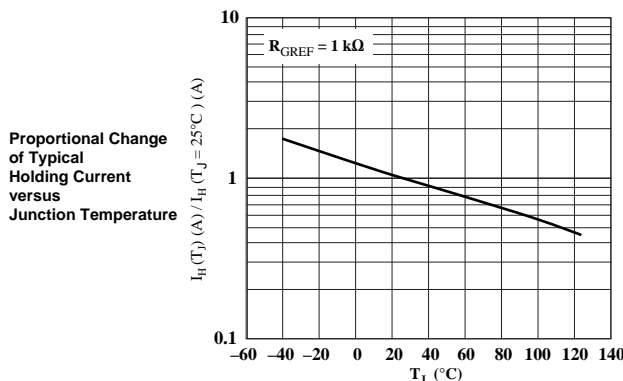
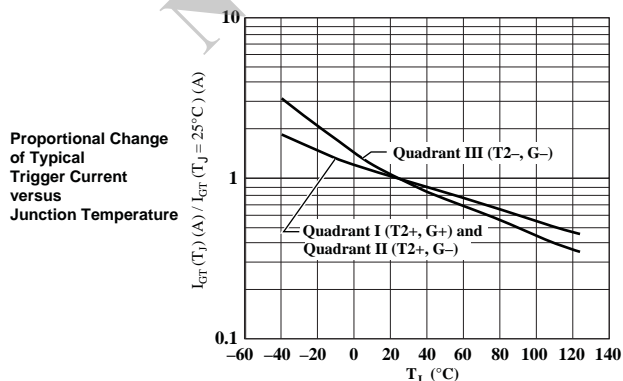
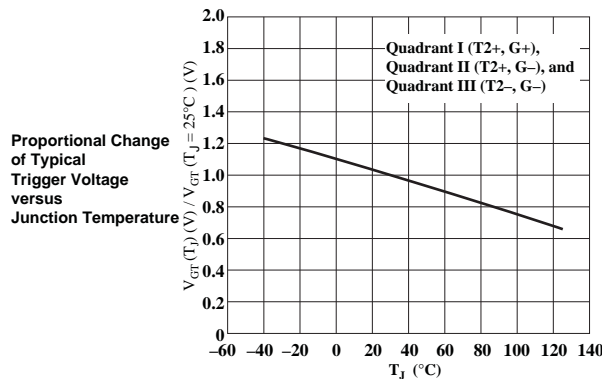
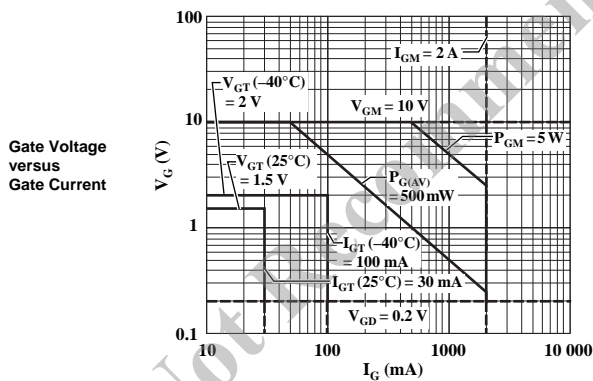
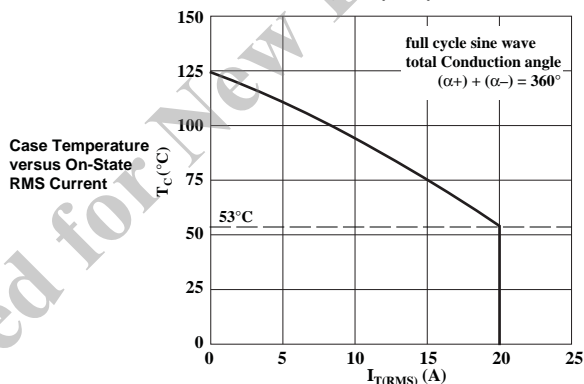
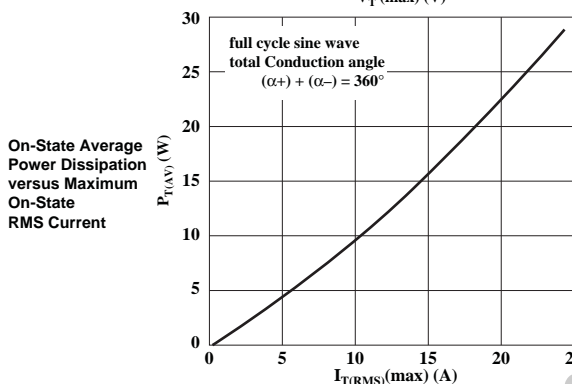
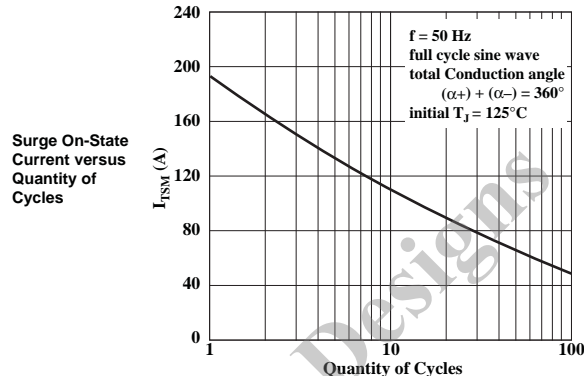
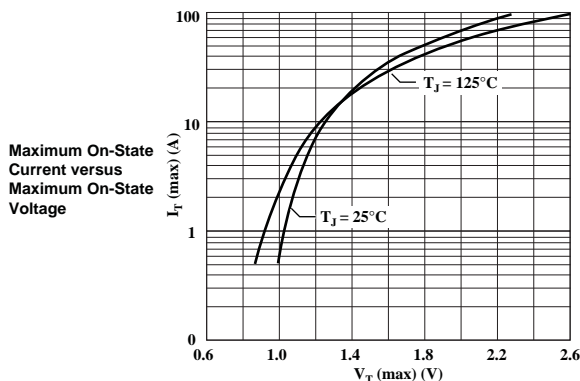


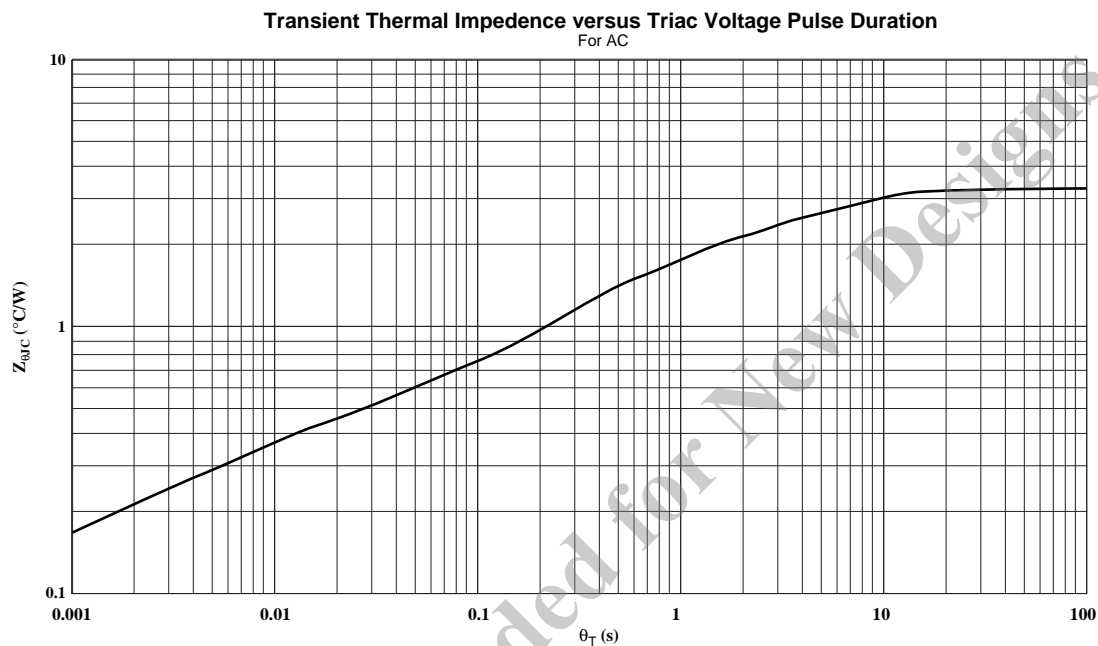
Polarities referenced to T1

Commutation Timing Diagrams



Performance Characteristics at $T_A = 25^\circ\text{C}$

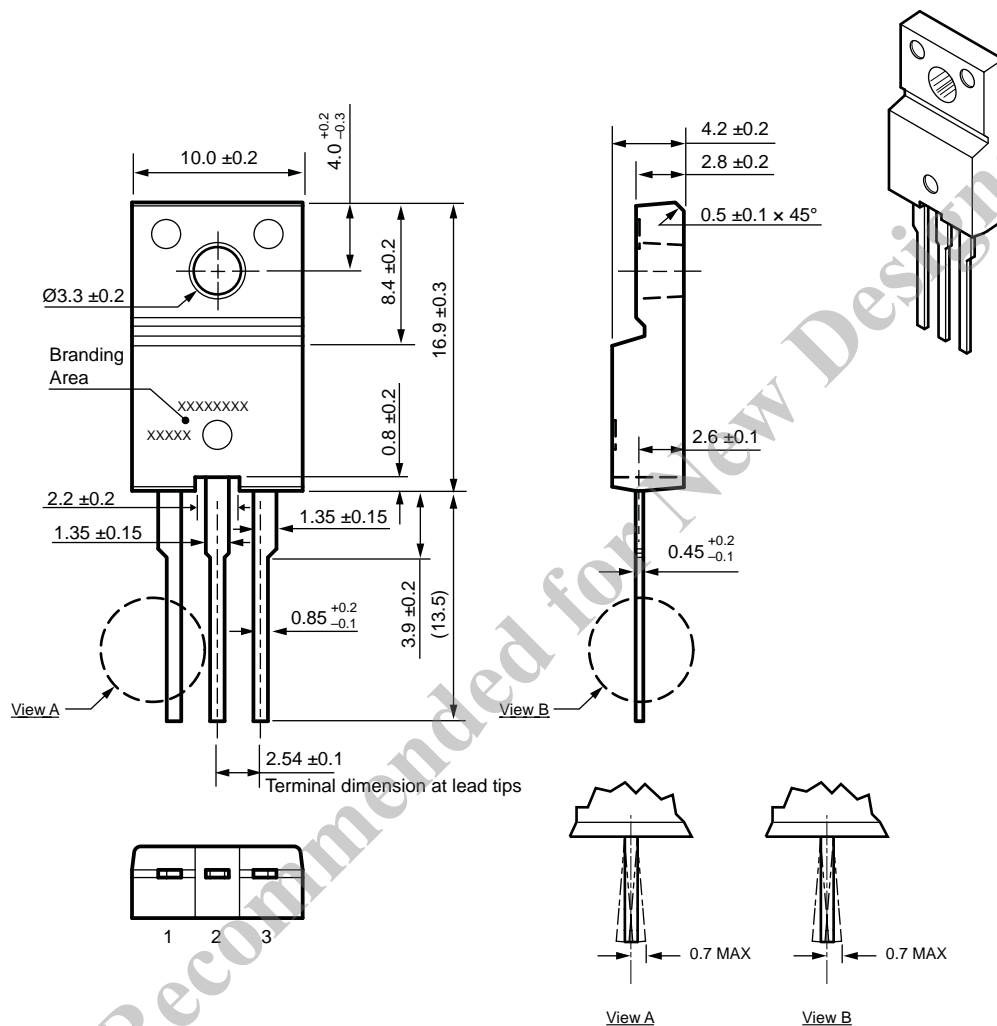




TMA20x Series

Triac (Bidirectional Triode Thyristor)

TO-220F Package Outline Drawing



Gate burr: 0.3 mm (max.), mold flash may appear at opposite side
 Terminal core material: Cu
 Terminal treatment: Ni plating and Pb-free solder dip
 Leadform: 600
 Package: TO-220F (FM20)

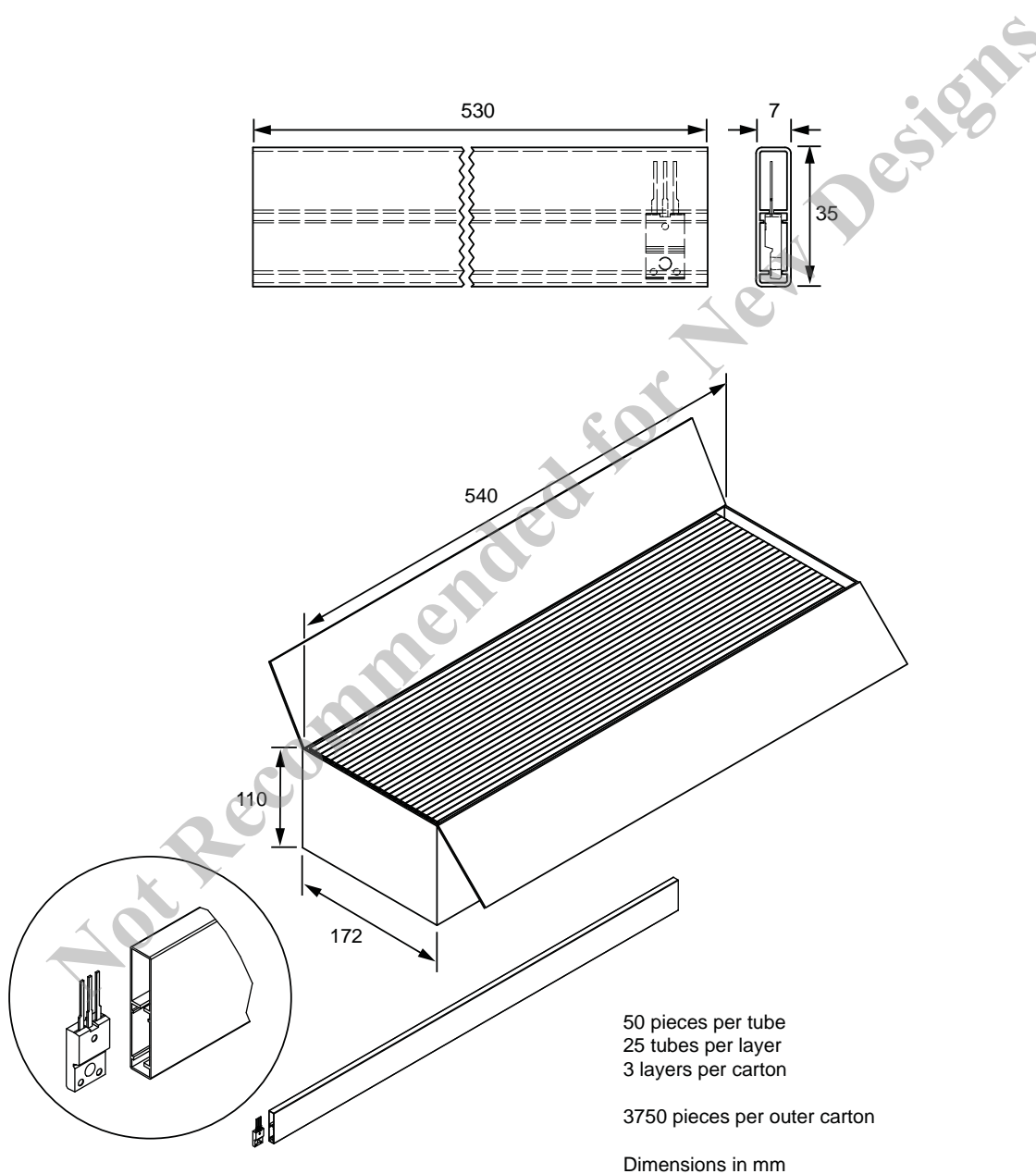
Branding codes (exact appearance at manufacturer discretion):
 1st line, type: MA20x
 2nd line, lot: YM
 Where: Y is the last digit of the year of manufacture
 M is the month (1 to 9, O, N, D)



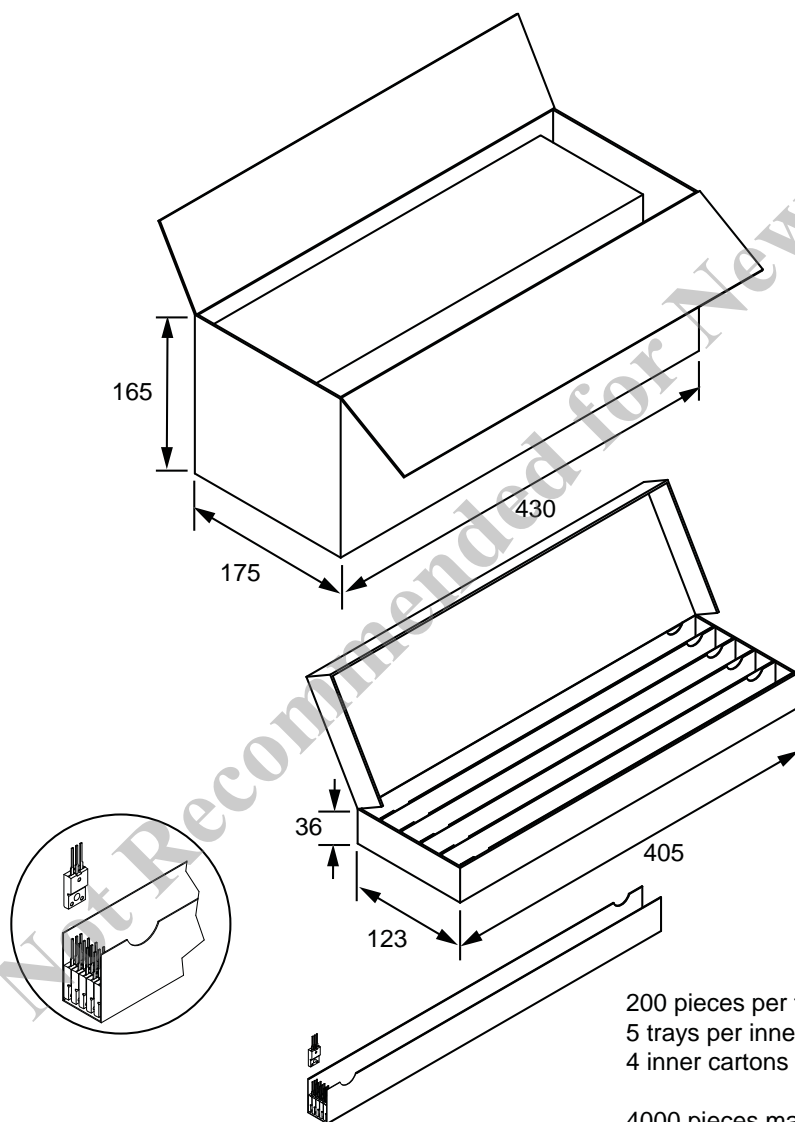
Leadframe plating Pb-free. Device meets RoHS requirements.

Packing Specification

Tube Packing



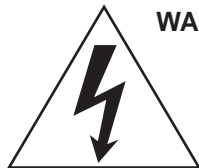
Bulk Packing



200 pieces per tray
5 trays per inner carton
4 inner cartons per outer carton

4000 pieces maximum per outer carton

Dimensions in millimeters



WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Coat the back surface of the product and both surfaces of the insulating plate to improve heat transfer between the product and the heatsink.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials
SC102	Dow Corning Toray Silicone Co., Ltd.

Heatsink Mounting Method

- **Torque When Tightening Mounting Screws.** Thermal resistance increases when tightening torque is low, and radiation effects are decreased. When the torque is too high, the screw can strip, the heatsink can be deformed, and distortion can arise in the product frame. To avoid these problems, observe the recommended tightening torques for this product package type 0.490 to 0.686 N•m (5 to 7 kgf•cm).
- **Diameter of Heatsink Hole:** < 4 mm. The deflection of the press mold when making the hole may cause the case material to crack at the joint with the heatsink. Please pay special attention for this effect.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
260±5°C 10 s
350±5°C 3 s
- Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

Sanken and Allegro reserve the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

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Users of Sanken products are requested to take, at their own risk, preventative measures including safety design of the equipment or systems against any possible injury, death, fires or damages to society due to device failure or malfunction.

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Anti radioactive ray design is not considered for the products listed herein.

Worldwide Contacts

Asia-Pacific

China

Sanken Electric Hong Kong Co., Ltd.

Suite 1026, Ocean Centre

Canton Road, Tsimshatsui

Kowloon, Hong Kong

Tel: 852-2735-5262, Fax: 852-2735-5494

Sanken Electric (Shanghai) Co., Ltd.

Room 3202, Maxdo Centre

Xingyi Road 8, Changning District

Shanghai, China

Tel: 86-21-5208-1177, Fax: 86-21-5208-1757

Taiwan Sanken Electric Co., Ltd.

Room 1801, 18th Floor

88 Jung Shiau East Road, Sec. 2

Taipei 100, Taiwan R.O.C.

Tel: 886-2-2356-8161, Fax: 886-2-2356-8261

Japan

Sanken Electric Co., Ltd.**Overseas Sales Headquarters**

Metropolitan Plaza Building

1-11-1 Nishi-Ikebukuro, Toshima-ku

Tokyo 171-0021, Japan

Tel: 81-3-3986-6164, Fax: 81-3-3986-8637

Korea

Sanken Electric Korea Co., Ltd.

Samsung Life Yeouido Building 16F

23-10, Yeouido-Dong, Yeongdeungpo-gu

Seoul 150-734, Korea

Tel: 82-2-714-3700, Fax: 82-2-3272-2145

Singapore

Sanken Electric Singapore Pte. Ltd.

150 Beach Road, #14-03 The Gateway West

Singapore 189720

Tel: 65-6291-4755, Fax: 65-6297-1744

Europe

Sanken Power Systems (UK) Limited

Pencoed Technology Park

Pencoed, Bridgend CF35 5HY, United Kingdom

Tel: 44-1656-869-100, Fax: 44-1656-869-162

North America

United States

Allegro MicroSystems, Inc.

115 Northeast Cutoff

Worcester, Massachusetts 01606, U.S.A.

Tel: 1-508-853-5000, Fax: 1-508-853-7895

Allegro MicroSystems, Inc.

14 Hughes Street, Suite B105

Irvine, California 92618, U.S.A.

Tel: 1-949-460-2003, Fax: 1-949-460-7837